

CORRECTION

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Correction: Wafer-scale reliable switching memory based on 2-dimensional layered organic–inorganic halide perovskite

Ja-Young Seo,^a Jaeho Choi,^b Hui-Seon Kim,^c Jaegyeom Kim,^d June-Mo Yang,^a Can Cuhadar,^a Ji Su Han,^b Seung-Joo Kim,^d Donghwa Lee,^{id} ^e Ho Won Jang ^{id} *^b and Nam-Gyu Park ^{id} *^a

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Correction for 'Wafer-scale reliable switching memory based on 2-dimensional layered organic–inorganic halide perovskite' by Ja-Young Seo, *et al.*, *Nanoscale*, 2017, DOI: 10.1039/c7nr05582j.

The name of one of the co-authors is given incorrectly in the published article. “Huo-Seon Kim” should instead be listed as “Hui-Seon Kim” as provided in the corrected author list above.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

^aSchool of Chemical Engineering, Energy Frontier Laboratory, Sungkyunkwan University, Suwon 16419, Korea. E-mail: npark@skku.edu

^bDepartment of Materials Science and Engineering, Research Center for Advanced Materials, Seoul National University, Seoul 08826, Korea. E-mail: hwjang@snu.ac.kr

^cLaboratory of Photomolecular Science, Institute of Chemical Sciences and Engineering, Ecole Polytechnique Federale de Lausanne, Lausanne, Switzerland

^dDepartment of Chemistry, Ajou University, Suwon 16499, Korea

^eDepartment of Materials Science and Engineering, Pohang University of Science and Technology (POSTECH), Pohang 37673, Korea

